

Phosphorus doped and defect modified graphitic carbon nitride for boosting photocatalytic hydrogen production

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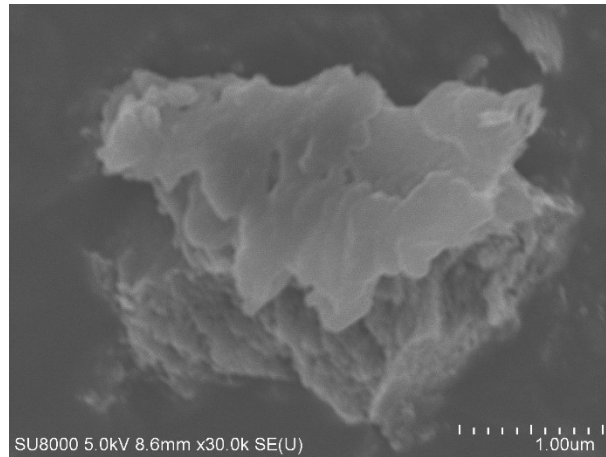


Fig. S1. SEM images of the as-prepared P-g-C₃N₄ sample.

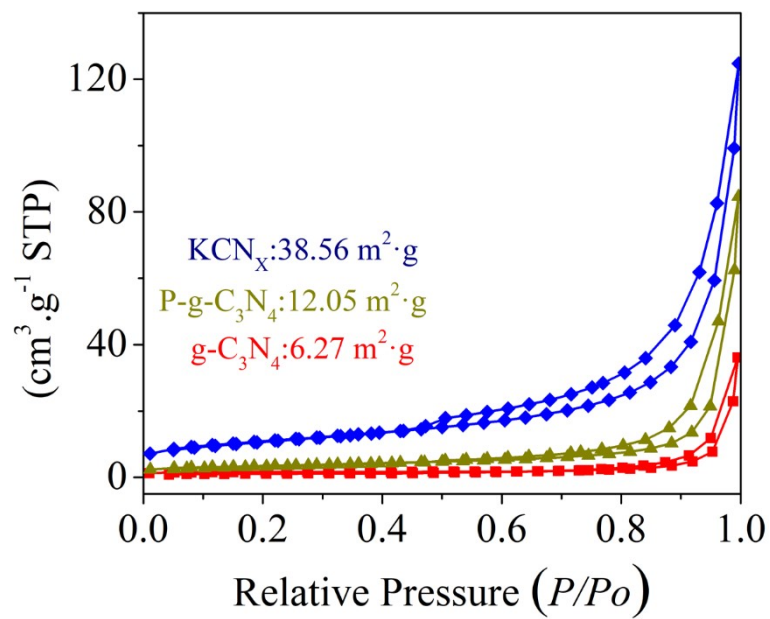


Fig S2: N₂ adsorption-desorption isotherms of pristine g-C₃N₄, P-g-C₃N₄ and KCN_x samples



Fig. S3. Digital photographs of the as-prepared $g\text{-C}_3\text{N}_4$ and $\text{P-g-C}_3\text{N}_4$ and PCN_x samples